

Data sheet acquired from Harris Semiconductor SCHS073C – Revised October 2003

CMOS 8-Channel Data Selector

High-Voltage Types (20-Volt Rating)

■ CD4512B is an 8-channel data selector featuring a three-state output that can interface directly with, and drive, data lines of bus-oriented systems.

The CD4512B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

CD4512B Types

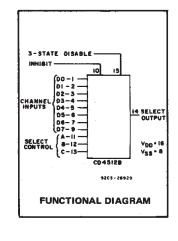
Features:

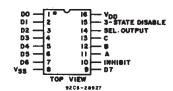
- **3**-state output
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 μA at 18 V over full packagetemperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range):

 Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Digital multiplexing
- Number-sequence generation
- Signal gating



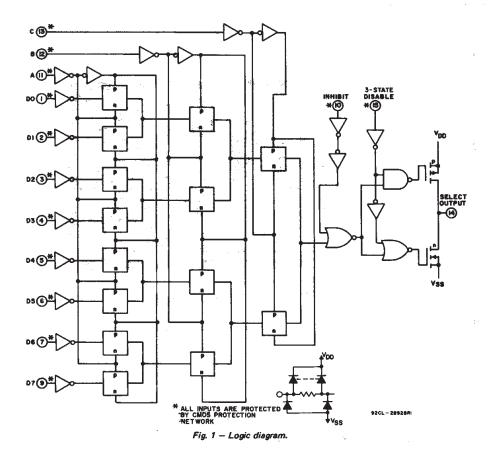


TERMINAL ASSIGNMENT

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

	LIN	IITS	AMUTO
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For T _A = Full Package Temperature Range)	3	18	· V



TRUTH TABLE

		1		1770-	
SEL	COM	NT.	INH	3-STATE	SEL
Α	В	С	114171	DISABLE	OUTPUT
0	0	0	0	0	D0
1	0	0	0	0	D1
0	1	0	0	0	D2
1	1	0	0	0	D3
0	0	1	0	0	D4
1	0	1	0	0	D 5
0	1	1	0	0	D6
1	1	1	0	0	D7
х	x	X	1	0	0
х	х	Ιx	х	1	High Z

1 = High Level

0 = Low Level

X = Don't Care

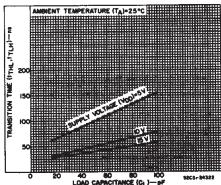


Fig. 2 — Typical transition time as a function of load capacitance.

CD4512B Types

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to V _{SS} Terminal)	
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to V _{DD} +0.5V	
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	
For T _A = +100°C to +125°C	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	
OPERATING-TEMPERATURE RANGE (T _A)55°C to +125°C	
STORAGE TEMPERATURE RANGE (T _{stg})65°C to +150°C	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C	

5 to	LOW (SIMK) CURRENT (I _{OL}) mA	A	WEN	EN	G.		(T 1 1 1 1 1 1 1 1 1		0 1100 1100	TA	GE	3				
	5 0		Ź		í		V2									

Fig. 3 — Typical output low (sink) current characteristics.

CHARAC- TERISTIC		DITIO	r :		MITS AT 1	NDICAT	ED TEM	PERAT	URES (°	C)	N I T S
	V _O (V)	V _{IN} (V)	V _{DD} (V)	55	–40	+85	+125	Min.	Typ.	Max.	3
Quiescent	_	0,5	5	5	5	150	150	-	0.04	5	
Device		0,10	10	10	10	300	300	-	0.04	10	μΑ
Current,	-	0,15	15	20	20	600	600	_	0.04	20	ļ
- DD Max.	_	0,20	20	100	100	3000	3000		0.08	100	İ
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_	
OL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	
Output High	4.6	0,5	5	-0.64	0.61	-0.42	-0.36	-0.51	-1	_	m
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_	
Current, IOH Min.	9.5	0,10	10	1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
13.5		0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_	
Output Voltage:	_	0,5	5		0.	.05	•	_	0	0.05	
Low-Level,	_	0,10	10		0.	.05		_	0	0.05	
VOL Max.	_	0,15	15		0.	.05		_	0	0.05	V
Output	_	0,5	5		4.	.95		4.95	5	- <u>-</u>	
Voltage: High-Level,	_	0,10	10		9	95		9.95	10	1	
VOH Min.	_	0,15	15	W. L. C	14	95		14.95	15	- F	
Input Low	0.5,4.5		5		4	1.5		-		1.5	
Voltage	1,9	_	10			3				3	
V _{IL} Max.	1.5,13.5	_	15			4		1	-	4	v
Input High	0.5,4.5	_	5			3.5		3.5	_	1	7.
Voltage,	1,9		10		162	7		7		-	
V _{IH} Min.	1.5,13.5		15			11		11	-	* -	
Input Current IN Max.	-	0,18	18	±0.1	±0.1	‡1	±1		±10 ⁻⁵	±0.1	μ
3-State Output Leakage Current IOUT Max.	0,18	0,18	18	±0.4	±0.4	±12	±12		±10 ⁻⁴	±0.4	μ

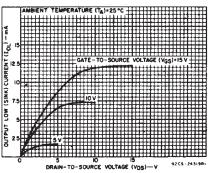


Fig. 4 — Minimum output low (sink) current characteristics.

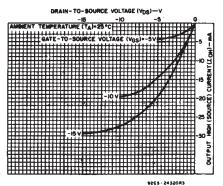


Fig. 5 — Typical output high (source) current characteristics.

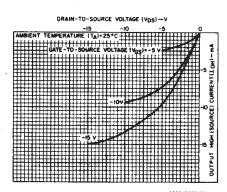


Fig. 6 — Minimum output high (source) current characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r,t_f = 20 ns, C_L = 50 pF, R_L = 200 $k\Omega$

CHARACTERISTIC	TEST CONDITIONS	LIN	MITS	UNITS
The second secon	V _{DD} (V)	Тур.	Max.	
Propagation Delay Time, tpHL, tpLH Inhibit to Output	5 10 15	140 70 50	280 140 100	
"A" Select to Output	5 10 15	200 85 60	400 170 120	ns
Data to Output	5 10 15	180 75 55	360 150 110	
3-State Disable Delay Time: [†] PZL, [†] PLZ, [†] PHZ, [†] PZH	5 10 15	60 30 20	120 60 40	ns
Transition Time, t _{THL} , t _{TLH}	5 10 15	100 50 40	200 100 80	ns
Input Capacitance, C _{IN} (Any Input)		5	7.5	pF

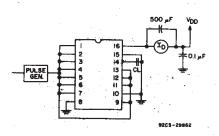


Fig. 9 - Dynamic power dissipation test circuit.

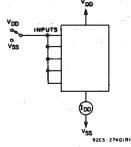


Fig. 10 - Quiescent device current test circuit.

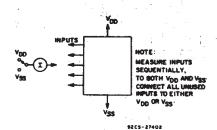


Fig. 11 - Input current test circuit.

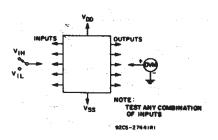
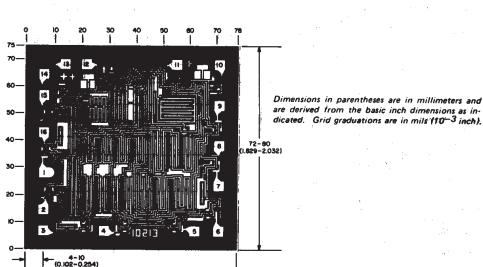


Fig. 12 - Input voltage test circuit.



Dimensions and pad layout for CD4512BH

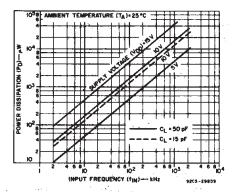


Fig. 7 — Typical dyanamic power dissipation as a function of frequency.

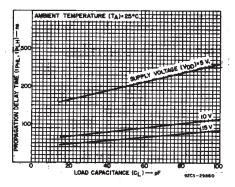


Fig. 8 — Typical propagation delay time as a function of load capacitance ("A" select to output).

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4512BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4512BE	Samples
CD4512BEE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4512BE	Samples
CD4512BF	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4512BF	Samples
CD4512BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4512BF3A	Samples
CD4512BM	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BM96G4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BMT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512B	Samples
CD4512BPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM512B	Samples
CD4512BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM512B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

PACKAGE OPTION ADDENDUM

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- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD4512B, CD4512B-MIL:

Catalog: CD4512B

Military: CD4512B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4512BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4512BNSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4512BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4512BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4512BNSR	SO	NS	16	2000	356.0	356.0	35.0
CD4512BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4512BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4512BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4512BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4512BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4512BM	D	SOIC	16	40	507	8	3940	4.32
CD4512BPW	PW	TSSOP	16	90	530	10.2	3600	3.5

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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